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## VS-21DQ06, VS-21DQ06-M3

**Vishay Semiconductors** 

# Cathode Anode

| PRODUCT SUMMARY                  |                  |  |  |  |  |
|----------------------------------|------------------|--|--|--|--|
| Package                          | DO-204AL (DO-41) |  |  |  |  |
| I <sub>F(AV)</sub>               | 2 A              |  |  |  |  |
| V <sub>R</sub>                   | 60 V             |  |  |  |  |
| V <sub>F</sub> at I <sub>F</sub> | 0.55 V           |  |  |  |  |
| I <sub>RM</sub> max.             | 10 mA at 125 °C  |  |  |  |  |
| T <sub>J</sub> max.              | 150 °C           |  |  |  |  |
| Diode variation                  | Single die       |  |  |  |  |
| E <sub>AS</sub>                  | 4.0 mJ           |  |  |  |  |

# Schottky Rectifier, 2 A

## FEATURES

- Low profile, axial leaded outline
- High frequency operation
- Very low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Compliant to RoHS Directive 2002/95/EC
- · Designed and qualified for commercial level
- Halogen-free according to IEC 61249-2-21 definition (-M3 only)

## DESCRIPTION

The VS-21DQ06... axial leaded Schottky rectifier has been optimized for very low forward voltage drop, with moderate leakage. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

| MAJOR RATINGS AND CHARACTERISTICS |                                |             |    |  |  |  |
|-----------------------------------|--------------------------------|-------------|----|--|--|--|
| SYMBOL                            | CHARACTERISTICS VALUES UNITS   |             |    |  |  |  |
| I <sub>F(AV)</sub>                | Rectangular waveform           | 2           | A  |  |  |  |
| V <sub>RRM</sub>                  |                                | 60          | N/ |  |  |  |
| V <sub>F</sub>                    | 2 Apk, T <sub>J</sub> = 125 °C | 0.55        | v  |  |  |  |
| TJ                                | Range                          | - 40 to 150 | °C |  |  |  |

| VOLTAGE RATINGS                      |                  |           |              |       |
|--------------------------------------|------------------|-----------|--------------|-------|
| PARAMETER                            | SYMBOL           | VS-21DQ06 | VS-21DQ06-M3 | UNITS |
| Maximum DC reverse voltage           | V <sub>R</sub>   | 60        | 60           | V     |
| Maximum working peak reverse voltage | V <sub>RWM</sub> | 00        | 00           | v     |

| ABSOLUTE MAXIMUM RATINGS                               |                    |   |   |        |       |  |
|--|--------------------|---|---|--------|-------|--|
| PARAMETER  | SYMBOL             | TEST CONDI  | TIONS   | VALUES | UNITS |  |
| Maximum average forward current See fig. 4             | I <sub>F(AV)</sub> | 50 % duty cycle at $T_C$ = 106 °C,  | rectangular waveform                              | 2      |       |  |
| Maximum peak one cycle<br>non-repetitive surge current |                    |   | Following any rated load condition and with rated | 340    | А     |  |
| See fig. 6   | IFSM               | 10 ms sine or 6 ms rect. pulse  | V <sub>RRM</sub> applied                          | 60     |       |  |
| Non-repetitive avalanche energy                        | E <sub>AS</sub>    | $T_{\rm J} = 25 \ ^{\circ}{\rm C}, \ I_{\rm AS} = 1 \ {\rm A}, \ {\rm L} = 8 \ {\rm mH}$  |   | 4.0    | mJ    |  |
| Repetitive avalanche current                           | I <sub>AR</sub>    | Current decaying linearly to zero in 1 $\mu$ s<br>Frequency limited by T <sub>J</sub> maximum V <sub>A</sub> = 1.5 x V <sub>R</sub> typical |   | 0.5    | А     |  |

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HALOGEN

**FREE** Available



## Vishay Semiconductors

| ELECTRICAL SPE | CIFICATIONS |
|----------------|-------------|
|----------------|-------------|

| ELECTRICAL SPECIFICATIONS       |                                |   |                                       |      |       |     |
|---------------------------------|--------------------------------|---|---------------------------------------|------|-------|-----|
| PARAMETER                       | SYMBOL                         | TEST CONDITIONS   |                                       | VAL  | UNITS |     |
| FARAMETER                       | STWBOL                         |   |                                       | TYP. | MAX.  |     |
|                                 |                                | 2 A   | T, = 25 °C                            | 0.53 | 0.60  | v   |
| Maximum forward voltage drop    | V <sub>FM</sub> <sup>(1)</sup> | 4 A   | 1j=25 C                               | 0.67 | 0.75  |     |
|                                 |                                | 2 A   | - T <sub>J</sub> = 125 °C             | 0.49 | 0.55  |     |
|                                 |                                | 4 A   |                                       | 0.61 | 0.67  |     |
| Maximum reverse leakage current | I (1)                          | T <sub>J</sub> = 25 °C  | V Deted V                             | 0.02 | 0.50  | m 4 |
| Maximum reverse leakage current | I <sub>RM</sub> <sup>(1)</sup> | T <sub>J</sub> = 125 °C   | V <sub>R</sub> = Rated V <sub>R</sub> | 7.0  | 10    | mA  |
| Typical junction capacitance    | C <sub>T</sub>                 | $V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz) 25 °C 120 |                                       |      | pF    |     |
| Typical series inductance       | L <sub>S</sub>                 | Measured lead to lead 5 mm from package body 8.0 nH             |                                       |      | nH    |     |

#### Note

 $^{(1)}\,$  Pulse width < 300  $\mu s,\,duty\,cycle$  < 2  $\,\%$ 

| THERMAL - MECHANICAL SPECIFICATIONS             |  |                                     |             |       |  |
|---|--|-------------------------------------|-------------|-------|--|
| PARAMETER                                       | SYMBOL   | TEST CONDITIONS                     | VALUES      | UNITS |  |
| Maximum junction and storage temperature range  | T <sub>J</sub> <sup>(1)</sup> , T <sub>Stg</sub> |                                     | - 40 to 150 | °C    |  |
| Maximum thermal resistance, junction to ambient | R <sub>thJA</sub>                                | DC operation<br>Without cooling fin | 100         | °C/W  |  |
| Typical thermal resistance, junction to lead    | R <sub>thJL</sub>                                | DC operation<br>See fig. 4          | 25          | -C/W  |  |
| Approvimete weight                              |  |                                     | 0.33        | g     |  |
| Approximate weight                              |  |                                     | 0.012       | oz.   |  |
| Marking device                                  |  | Case style DO-204AL (D-41)          | 21D         | Q06   |  |

#### Note

 $^{(1)} \quad \frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}} \quad \text{thermal runaway condition for a diode on its own heatsink}$ 



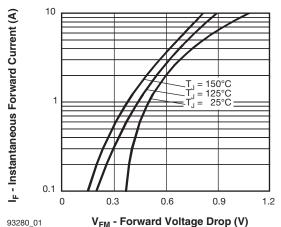
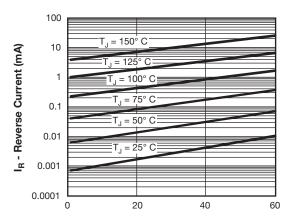
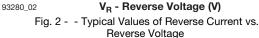
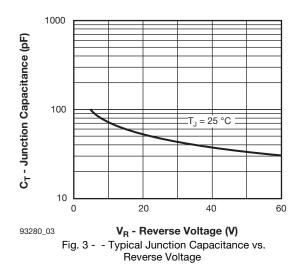


Fig. 1 - Maximum Forward Voltage Drop Characteristics

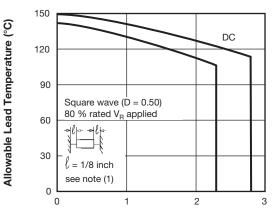






## VS-21DQ06, VS-21DQ06-M3

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93280\_04 I<sub>F(AV)</sub> - Average Forward Current (A) Fig. 4 - Maximum Allowable Lead Temperature vs. Average Forward Current

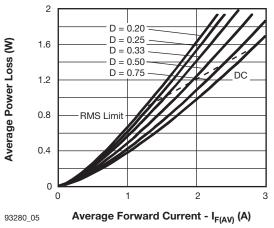
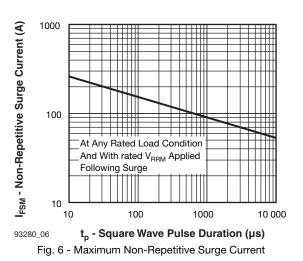


Fig. 5 - Forward Power Loss Characteristics



Note

<sup>(1)</sup> Formula used:  $T_L = T_J - (Pd + Pd_{REV}) \times R_{thJL}$ ;

Pd = Forward power loss =  $I_{F(AV)} \times V_{FM}$  at ( $I_{F(AV)}/D$ ) (see fig. 5); Pd<sub>REV</sub> = Inverse power loss =  $V_{R1} \times I_R$  (1 - D);  $I_R$  at  $V_{R1}$  = 80 % rated  $V_R$ 

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# VS-21DQ06, VS-21DQ06-M3

## Vishay Semiconductors

## **ORDERING INFORMATION TABLE**

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| Device code | V                             | S- | 21     | D        | Q         | 06       | TR     | -M3     |
|-------------|-------------------------------|----|--------|----------|-----------|----------|--------|---------|
|             |                               | )  | 2      | 3        | 4         | 5        | 6      | 7       |
|             | 1                             | -  | Visha  | ay Semi  | conducte  | ors proc | luct   |         |
|             | 2                             | -  | 21 =   | Current  | Rating,   | 2 A      |        |         |
|             | 3                             | -  | D = [  | DO-41 p  | ackage    |          |        |         |
|             | 4                             | -  | Q = \$ | Schottky | Q seri    | es       |        |         |
|             | 5 - 06 = Voltage rating: 60 V |    |        |          |           |          |        |         |
|             | 6                             | -  | • TR   | = Tape   | and ree   | l packaç | ge     |         |
|             |                               |    | • TB   | = Tape   | and am    | mo box   | packag | е       |
|             |                               |    | • Nor  | ne = Bul | lk packa  | ge       |        |         |
|             | 7                             | -  | Envi   | ronmen   | tal digit |          |        |         |
|             |                               |    | • No   | one = Le | ad (Pb)-  | free an  | d RoHS | complia |
|             |                               |    |        |          |           |          |        |         |

• -M3 = Halogen-free, RoHS compliant, and terminations lead (Pb)-free

| ORDERING INFORMATION (Example) |                  |                        |                       |  |  |  |
|--------------------------------|------------------|------------------------|-----------------------|--|--|--|
| PREFERRED P/N                  | QUANTITY PER T/R | MINIMUM ORDER QUANTITY | PACKAGING DESCRIPTION |  |  |  |
| VS-21DQ06                      | 1000             | 1000                   | Bulk                  |  |  |  |
| VS-21DQ06TR                    | 5000             | 5000                   | Tape and reel         |  |  |  |
| VS-21DQ06TB                    | 3000             | 3000                   | Tape and ammo box     |  |  |  |
| VS-21DQ06-M3                   | 1000             | 1000                   | Bulk                  |  |  |  |
| VS-21DQ06TR-M3                 | 5000             | 5000                   | Tape and Reel         |  |  |  |
| VS-21DQ06TB-M3                 | 3000             | 3000                   | Tape and ammo box     |  |  |  |

| LINKS TO RELATED DOCUMENTS |                          |  |  |  |  |
|----------------------------|--------------------------|--|--|--|--|
| Dimensions                 | www.vishay.com/doc?95241 |  |  |  |  |
| Part marking information   | www.vishay.com/doc?95304 |  |  |  |  |
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27.0 (1.06) MIN. (2 places)

1.27 (0.050) MAX.

Flash (2 places)

2.70 (0.106)

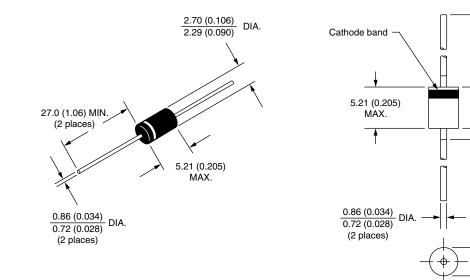
2.29 (0.090)

DIA.



Axial DO-204AL (DO-41)

#### **DIMENSIONS** in millimeters (inches)





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